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## STPS20L40C

## Low drop power Schottky rectifier

### Main product characteristics

I <sub>F(AV)</sub>	2 x 10 A
V <sub>RRM</sub>	40 V
T <sub>j</sub> (max)	150° C
V <sub>F</sub> (max)	0.5 V

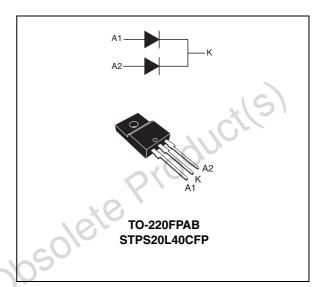
#### Features and benefits

- Low forward voltage drop meaning very small conduction losses
- Low dynamic losses as a result of the schottky barrier
- Insulated package: TO-220FPAB insulating voltage = 200 V DC capacitance = 12 pF
- Avalanche capability specified

## Description

Dual center tap Schottky rectifiers designed for high frequency switched mode power supplies and DC to DC converters.

These devices are intended for use in low voltage, high frequency inverters, free-wheeling and polarity protection applications.



## 1 Characteristics

	Absolute nutrings (ininiting value	88)			
Symbol	Parameter	Value	Unit		
V <sub>RRM</sub>	Repetitive peak reverse voltage			40	V
I <sub>F(RMS)</sub>	RMS forward voltage			30	А
I <sub>F(AV)</sub>	Average forward current	$ \begin{array}{c c} T_c = 115^{\circ} \ C \\ \delta = 0.5 \end{array} \begin{array}{c} \mbox{Per diode} \\ \mbox{Per device} \end{array} $		10 20	А
I <sub>FSM</sub>	Surge non repetitive forward current	t <sub>p</sub> = 10 ms Si	nusoidal	180	А
I <sub>RRM</sub>	Peak repetitive reverse current	t <sub>p</sub> = 2 μs squa	are F = 1 kHz	110	A
I <sub>RSM</sub>	Non repetitive peak reverse current	t <sub>p</sub> = 100 μs s	quare	2	А
P <sub>ARM</sub>	Repetitive peak avalanche power $t_p = 1 \ \mu s \ T_j = 25^{\circ}C$			4000	W
T <sub>stg</sub>	Storage temperature range -65				°C
Тj	Maximum operating junction temperature <sup>(1)</sup> 150			150	°C
dV/dt	Critical rate of rise of reverse voltage			10000	V/µs
dPtot	1				

#### Table 1. Absolute Ratings (limiting values)

1.  $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$  condition to avoid thermal runaway for a diode on its own heatsink

### Table 2.Thermal resistances

Symbol	Parameter	Value	Unit	
R <sub>th(j-c)</sub>	Junction to case	Per diode Total Coupling	4.5 3.5 2.5	°C/W

When the diodes 1 and 2 are used simultaneously :

 $\Delta$ Tj(diode 1) = P(diode1) x R<sub>th(j-c)</sub>(Per diode) + P(diode 2) x R<sub>th(c)</sub>.

 Table 3.
 Static electrical characteristics (per diode)

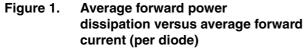
	Table 0.							
10	Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
Obsoli	ا <sub>R</sub> <sup>(1)</sup>	Reverse leakage current	$T_j = 25^\circ C$	V <sub>R</sub> = V <sub>RRM</sub>			0.7	mA
			$T_j = 100^\circ C$			15	35	mA
	V <sub>F</sub> <sup>(1)</sup>	Forward voltage drop	$T_j = 25^\circ C$	I <sub>F</sub> = 10 A			0.55	
			$T_j = 125^\circ C$	I <sub>F</sub> = 10 A		0.44	0.5	v
			$T_j = 25^\circ C$	I <sub>F</sub> = 20 A			0.73	v
			$T_j = 125^\circ C$	I <sub>F</sub> = 20 A		0.62	0.72	

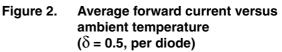
1. Pulse test: tp = 380  $\mu$ s,  $\delta$  < 2%

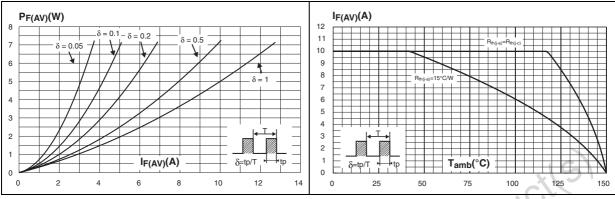
To evaluate the conduction losses use the following equation:

 $P = 0.28 \text{ x } I_{F(AV)} + 0.022 I_{F}^{2}(RMS)$ 









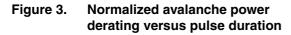


Figure 4. Normalized avalanche power derating versus junction temperature

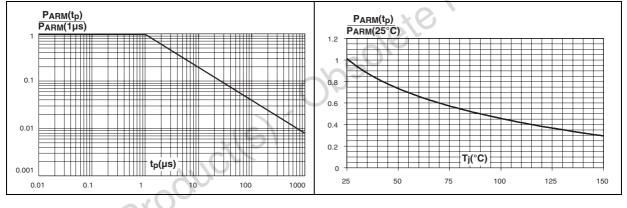
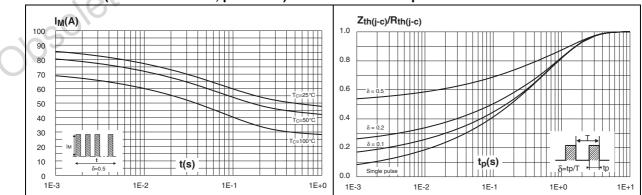


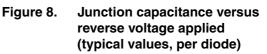
Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values, per diode)

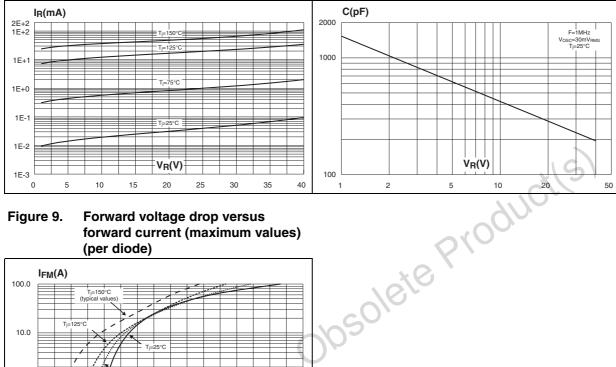
Figure 6. Relative variation of thermal impedance junction to case versus pulse duration



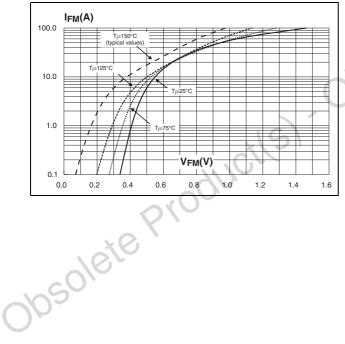


#### Reverse leakage current versus Figure 7. reverse voltage applied (typical values, per diode)





#### Figure 9. Forward voltage drop versus forward current (maximum values) (per diode)



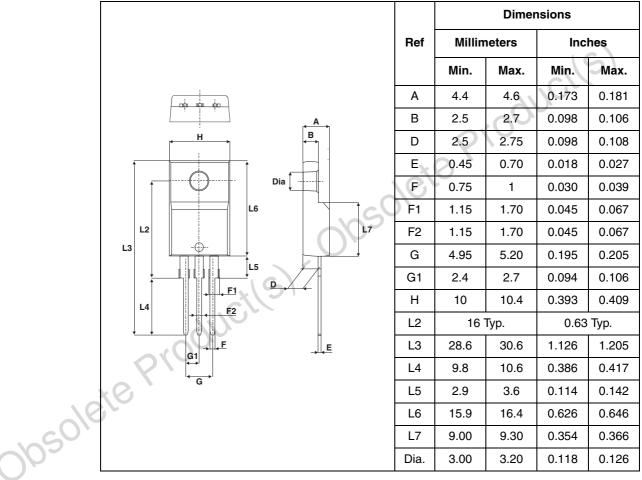
2



## 2 Package Information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 Nm
- Maximum torque value: 0.70 Nm

Table 4.TO-220FPAB dimensions



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.



## **3** Ordering information

Ordering type	Marking	Marking Package		Base qty	Delivery mode	
STPS20L40CFP	STPS20L40CFP	TO-220FPAB	2 g	50	Tube	

## 4 Revision history

			16
	Date	Revision	Description of Changes
	Jul_2003	4B	Last release.
	26-Mar-2007	5	Removed ISOWATT, TO-220AB and TO-247 packages.
obsole	ste Prodi	Jot(S)	obsolete

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